imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



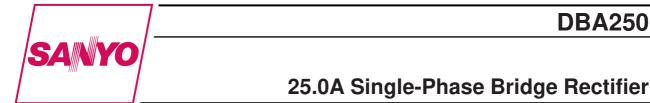
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Diffused Junction Silicon Diode

DBA250

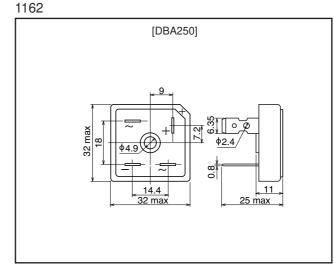


Features

- · Plastic molded structure.
- · Glass passivation for high reliability.
- Peak reverse voltage : VRM=200, 600V.
- Average rectified current : IO=25.0A.

Package Dimensions

unit : mm



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	DBA250C	DBA250G	Unit
Peak Reverse Voltage	VRM		200	600	V
Average Recitified Current	IO	Ta=40°C		6.0	A
		Ta=40°C, with a 300×300×3.0mm ³ Cu fin	\rightarrow	25.0	А
Surge Forward Current	IFSM	50Hz sine wave, 1 cycle	→	400	A
Junction Temperature	Tj			150	°C
Storage Temperature	Tstg		→	-40 to +150	°C
Insulation Voltage	VIS		\rightarrow	2	kV

Electrical Characteristics at Ta=25°C

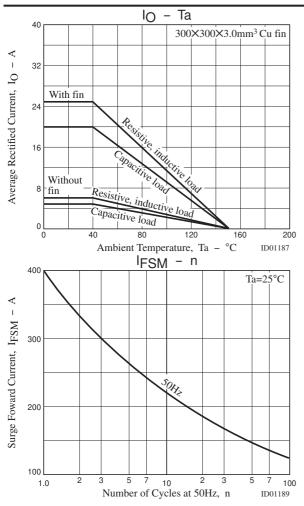
Devemeter	Symbol	Conditions	Ratings			Linit
Parameter			min	typ	max	Unit
Forward Voltage	VF	IF=12.5A*			1.05	V
Reverse Current	IR	VR : At each VRM*			10	μA
Thermal Resistance	Rth(j-c)	Junction-Case			1.5	°C/W

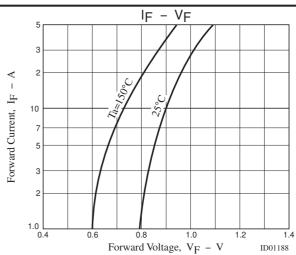
Note : Tightening torque : 0.98N·m max.

Note* : Per constituent element of bridge.

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